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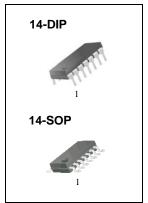
LM324/LM324A, LM2902/LM2902A Quad Operational Amplifier

Features

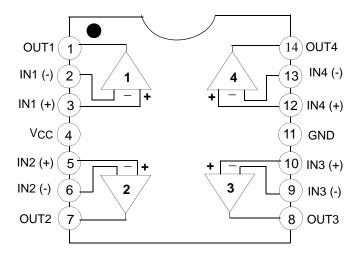
- Internally Frequency Compensated for Unity Gain
- Large DC Voltage Gain: 100dB
- Wide Power Supply Range: LM324/LM324A: 3V~32V (or ±1.5 ~ 16V) LM2902/LM2902A: 3V~26V (or ±1.5V ~ 13V)
- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V to VCC -1.5V
- Power Drain Suitable for Battery Operation

Description

The LM324/LM324A, LM2902/LM2902A consist of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide voltage range. operation from split power supplies is also possible so long as the difference between the two supplies is 3 volts to 32 volts. Application areas include transducer amplifier, DC gain blocks and all the conventional OP Amp circuits which now can be easily implemented in single power supply systems.

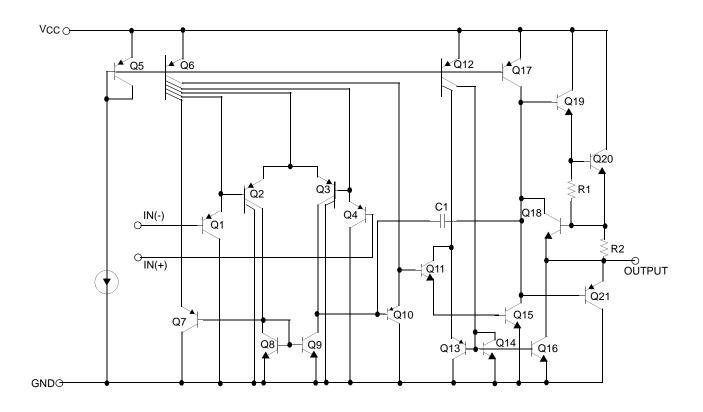


Internal Block Diagram



Schematic Diagram

(One Section Only)



Absolute Maximum Ratings

Parameter	Symbol	LM324/LM324A	LM2902/LM2902A	Unit
Power Supply Voltage	Vcc	±16 or 32	±13 or 26	V
Differential Input Voltage	VI(DIFF)	32	26	V
Input Voltage	VI	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND Vcc≤15V, TA=25°C(one Amp)	-	Continuous	Continuous	-
Power Dissipation, T _A =25°C 14-DIP 14-SOP	PD	1310 640	1310 640	mW
Operating Temperature Range	TOPR	0 ~ +70	-40 ~ +85	°C
Storage Temperature Range	TSTG	-65 ~ +150	-65 ~ +150	°C

Thermal Data

Parameter	Symbol	Value	Unit
Thermal Resistance Junction-Ambient Max. 14-DIP 14-SOP	Rθja	95 195	°C/W

Electrical Characteristics

(VCC = 5.0V, VEE = GND, $T_A = 25$ °C, unless otherwise specified)

Doromotor	Cumbal	Conditions			LM324	,	LM2902			
Parameter	Symbol	Co	Conditions		Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO		V to VCC -1.5V 1.4V, RS = 0Ω	1	1.5	7.0	-	1.5	7.0	mV
Input Offset Current	lio	VCM = 0	V	ı	3.0	50	-	3.0	50	nA
Input Bias Current	IBIAS	VCM = 0	V	-	40	250	-	40	250	nA
Input Common-Mode Voltage Range	VI(R)	Note1		0	-	VCC -1.5	0	-	VCC -1.5	V
Supply Current	Icc		/CC = 30V 2,VCC=26V)	-	1.0	3	-	1.0	3	mA
		R _L = ∞,\	/cc = 5V	-	0.7	1.2	-	0.7	1.2	mA
Large Signal Voltage Gain	G∨		5V,RL=2kΩ 1V to 11V	25	100	-	25	100	-	V/mV
	VO(H) Note	Noted	$R_L = 2k\Omega$	26	-	-	22	-	-	V
Output Voltage Swing		Note	R _L =10kΩ	27	28	-	23	24	-	V
	VO(L)	VCC = 5	VCC = 5V, $RL=10kΩ$		5	20	-	5	100	mV
Common-Mode Rejection Ratio	CMRR		-		75	-	50	75	-	dB
Power Supply Rejection Ratio	PSRR		-	65	100	-	50	100	-	dB
Channel Separation	CS	f = 1kHz (Note2)	to 20kHz	-	120	-	-	120	-	dB
Short Circuit to GND	Isc	Vcc = 1	5V	-	40	60	-	40	60	mA
	ISOURCE	V _{I(+)} = 1V, V _{I(-)} = 0V V _{CC} = 15V, V _{O(P)} = 2V		20	40	-	20	40	-	mA
Output Current	VCC = 1		,	10	13	-	10	13	-	mA
	ISINK	VI(+) = 0V, VI(-) = 1V VCC = 15V, VO(R) = 200mV		12	45	-	-	-	-	μА
Differential Input Voltage	VI(DIFF)		-	•	-	Vcc	-	-	Vcc	V

^{1.} VCC=30V for LM324 , VCC=26V for LM2902

^{2.} This parameter, although guaranteed, is not 100% tested in production.

Electrical Characteristics (Continued)

(VCC = 5.0V, VEE = GND, unless otherwise specified)

The following specification apply over the range of $0^{\circ}C \le T_A \le +70^{\circ}C$ for the LM324; and the -40°C $\le T_A \le +85^{\circ}C$ for the LM2902

Denomotor	Compleal	nbol Conditions		LM324			I	11		
Parameter	Symbol	Co	Conditions		Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	$V_{ICM} = 0V \text{ to } V_{CC} -1.5V$ $V_{O(P)} = 1.4V, R_{S} = 0\Omega$ (Note1)		-	-	9.0	-	-	10.0	mV
Input Offset Voltage Drift	ΔVΙΟ/ΔΤ	$Rs = 0\Omega$	(Note2)	-	7.0	-	-	7.0	-	μV/°C
Input Offset Current	lio	VCM = 0	V	-	-	150	-	-	200	nA
Input Offset Current Drift	ΔΙΙΟ/ΔΤ	$R_S = 0\Omega$	(Note2)	-	10	-	-	10	-	pA/°C
Input Bias Current	IBIAS	VCM = 0	VCM = 0V		-	500	-	-	500	nA
Input Common-Mode Voltage Range	VI(R)	Note1		0	-	VCC -2.0	0	-	VCC -2.0	V
Large Signal Voltage Gain	GV		$V_{CC} = 15V, R_L = 2.0kΩ$ $V_{O(P)} = 1V \text{ to } 11V$		-	-	15	-	-	V/mV
	Vous	Note1	RL=2kΩ	26	-	-	22	-	-	V
Output Voltage Swing	VO(H)	Note	R _L =10kΩ	27	28	-	23	24	-	V
	VO(L)	VCC = 5'	V, RL=10kΩ	-	5	20	-	5	100	mV
Output Current	ISOURCE	VI(+) = 1V, VI(-) = 0V VCC = 15V, VO(P) = 2V		10	20	-	10	20	-	mA
Output Guiterit	ISINK	V _{I(+)} = 0V, V _{I(-)} = 1V V _{CC} = 15V, V _{O(P)} = 2V		5	8	-	5	8	-	mA
Differential Input Voltage	VI(DIFF)		-		-	Vcc	-	-	Vcc	V

- 1. VCC=30V for LM324 , VCC=26V for LM2902
- 2. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (Continued)

(VCC = 5.0V, VEE = GND, $T_A = 25$ °C, unless otherwise specified)

Danamatan	Symbol Conditions		L	_M324	A	L	l lmit			
Parameter	Symbol	Co	naitions	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	Vio		V to VCC -1.5V 1.4V, RS = 0Ω	-	1.5	3.0	-	1.5	2.0	mV
Input Offset Current	lio	VCM = 0	V	-	3.0	30	-	3.0	50	nA
Input Bias Current	IBIAS	VCM = 0	V	1	40	100	-	40	250	nA
Input Common-Mode Voltage Range	VI(R)	VCC = 3	0V	0	-	VCC -1.5	0	-	VCC -1.5	V
Supply Current	Icc		0V, RL = ∞ 2,VCC=26V)	ı	1.5	3	-	1.0	3	mA
		Vcc = 5	$VCC = 5V, RL = \infty$		0.7	1.2	-	0.7	1.2	mA
Large Signal Voltage Gain	Gv		5V, R _L = 2kΩ 1V to 11V	25	100	-	25	100	-	V/mV
Output Voltage Swing	VO(H)	Note1	$R_L = 2k\Omega$	26	-	-	22	-	-	V
			$R_L = 10k\Omega$	27	28	-	23	24	•	V
	VO(L)	Vcc = 5	$VCC = 5V, RL=10k\Omega$		5	20	-	5	100	mV
Common-Mode Rejection Ratio	CMRR		-		85	-	50	75	-	dB
Power Supply Rejection Ratio	PSRR		-	65	100	-	50	100	-	dB
Channel Separation	CS	f = 1kHz (Note2)	to 20kHz	-	120	-	-	120	-	dB
Short Circuit to GND	Isc	VCC = 1	5V	-	40	60	-	40	60	mA
	ISOURCE		$V, V_{I(-)} = 0V$ $V, V_{O(P)} = 2V$	20	40	-	20	40	-	mA
Output Current		V _I (+) = 0V, V _I (-) = 1V VCC = 15V, V _O (P) = 2V		10	20	-	10	13	-	mA
	ISINK		VV, VI(-) = 1V 5V, VO(P) =	12	50	-	-	-	-	μΑ
Differential Input Voltage	VI(DIFF)		-	-	-	Vcc	-	-	Vcc	V

^{1.} VCC=30V for LM324A ; VCC=26V for LM2902A

^{2.} This parameter, although guaranteed, is not 100% tested in production.

Electrical Characteristics (Continued)

($V_{CC} = 5.0V$, $V_{EE} = GND$, unless otherwise specified)

The following specification apply over the range of $0^{\circ}C \le T_A \le +70^{\circ}C$ for the LM324A ; and the -40°C $\le T_A \le +85^{\circ}C$ for the LM2902A

Parameter	Symbol	Conditions		L	_M324	Ą	LM2902A			
Parameter	Symbol	Co	Conditions		Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	Vio	-	$V_{CM} = 0V \text{ to } V_{CC} -1.5V$ $V_{O(P)} = 1.4V, R_S = 0\Omega$ (Note1)		-	5.0	-	-	6.0	mV
Input Offset Voltage Drift	ΔV10/ΔΤ	$Rs = 0\Omega$	(Note2)	-	7.0	30	-	7.0	-	μV/°C
Input Offset Current	lio	VCM = 0	V	-	-	75	-	-	200	nA
Input Offset Current Drift	ΔΙΙΟ/ΔΤ	$Rs = 0\Omega$	(Note2)	-	10	300	-	10	-	pA/°C
Input Bias Current	IBIAS		-	-	40	200	-	-	500	nA
Input Common-Mode Voltage Range	VI(R)	Note1		0	-	VCC -2.0	0	-	VCC -2.0	V
Large Signal Voltage Gain	G∨	Vcc = 1	5V, R _L = 2.0kΩ	15	-	-	15	-	-	V/mV
	\/o(1)	Note1	$R_L = 2k\Omega$	26	-	-	22	-	-	V
Output Voltage Swing	VO(H)	Note	$RL = 10k\Omega$	27	28	-	23	24	-	V
	VO(L)	$VCC = 5V$, $RL = 10k\Omega$		-	5	20	-	5	100	mV
Output Current	ISOURCE	V _I (+) = 1V, V _I (-) = 0V VCC = 15V, V _O (P) = 2V		10	20	-	10	20	-	mA
Output Current	ISINK	VI(+) = 0V, VI(-) = 1V VCC = 15V, VO(P) = 2V		5	8	-	5	8	-	mA
Differential Input Voltage	VI(DIFF)		-	-	-	Vcc	-	•	Vcc	V

- 1. VCC=30V for LM324A; VCC=26V for LM2902A.
- 2. These parameters, although guaranteed, are not 100% tested in production.

Typical Performance Characteristics

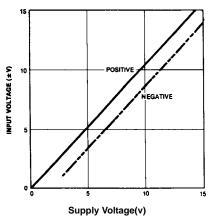


Figure 1. Input Voltage Range vs Supply Voltage

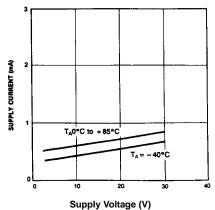


Figure 3. Supply Current vs Supply Voltage

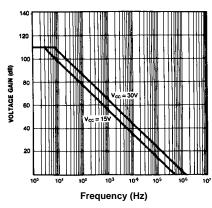


Figure 5. Open Loop Frequency Response

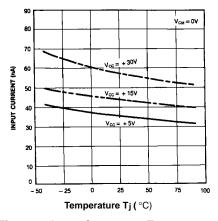


Figure 2. Input Current vs Temperature

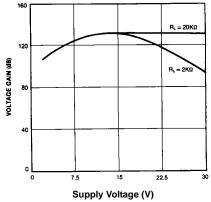


Figure 4. Voltage Gain vs Supply Voltage

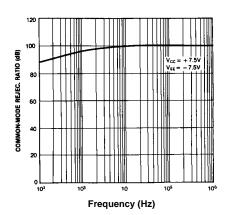


Figure 6. Common mode Rejection Ratio

Typical Performance Characteristics (Continued)

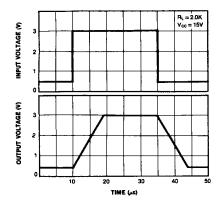


Figure 7. Voltage Follower Pulse Response

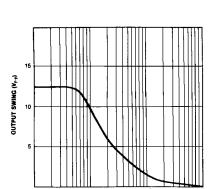


Figure 9. Large Signal Frequency Response

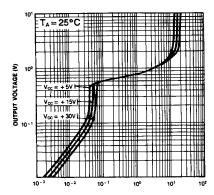


Figure 11. Output Characteristics vs Current Sinking

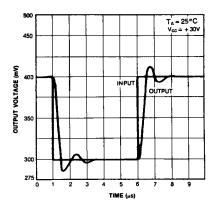


Figure 8. Voltage Follower Pulse Response (Small Signal)

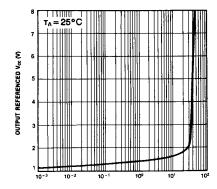


Figure 10. Output Characteristics vs Current Sourcing

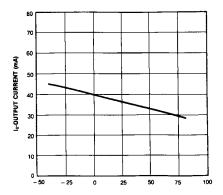
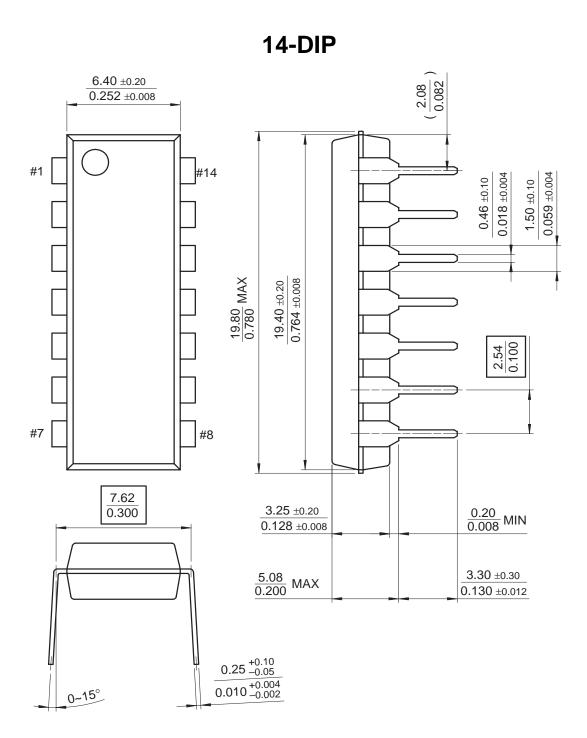


Figure 12. Current Limiting vs Temperature

Mechanical Dimensions

Package

Dimensions in millimeters

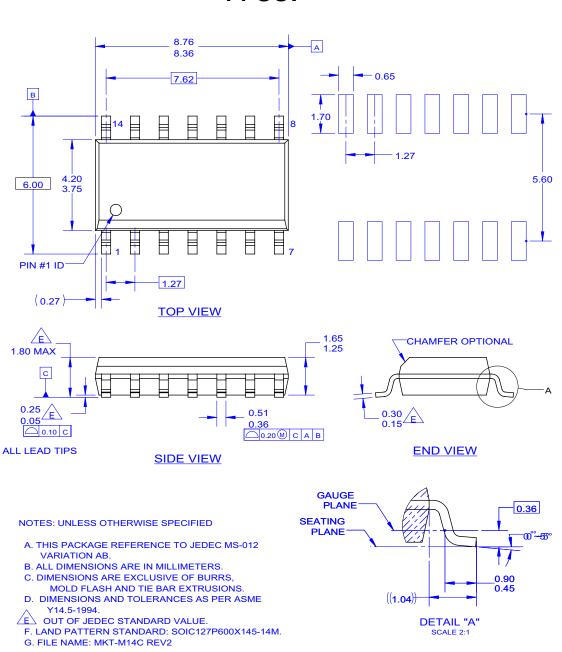


Mechanical Dimensions (Continued)

Package

Dimensions in millimeters

14-SOP



Ordering Information

Product Number	Package	Operating Temperature
LM324N	14-DIP	
LM324AN	14-011	0 ~ +70°C
LM324M	14-SOP	0 4 470 0
LM324AM	14-301	
LM2902N	14-DIP	
LM2902M	14-SOP	-40 ~ +85°C
LM2902AM	14-301	

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